

RJH60D5DPM

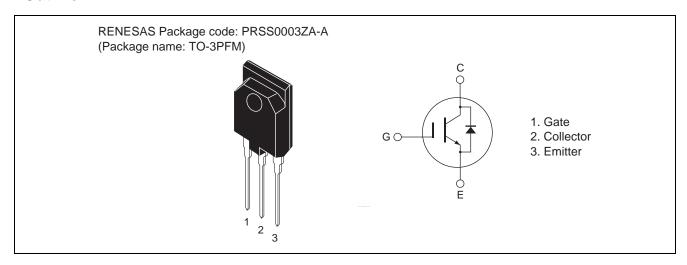
600V - 37A - IGBT Application: Inverter

R07DS0174EJ0200 Rev.2.00 Apr 19, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.6~V$ typ. (at $I_C=37~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 40 ns typ. (at V_{CC} = 300 V, V_{GE} = 15 V, I_C = 37 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I _C	75	Α
	Tc = 100°C	I _C	37	А
Collector peak current		ic(peak) Note1	150	Α
Collector to emitter diode forward current		I _{DF}	30	Α
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	120	Α
Collector dissipation		P _C Note2	45	W
Junction to case thermal resistance (IGBT)		θj-c Note2	2.78	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	3.95	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

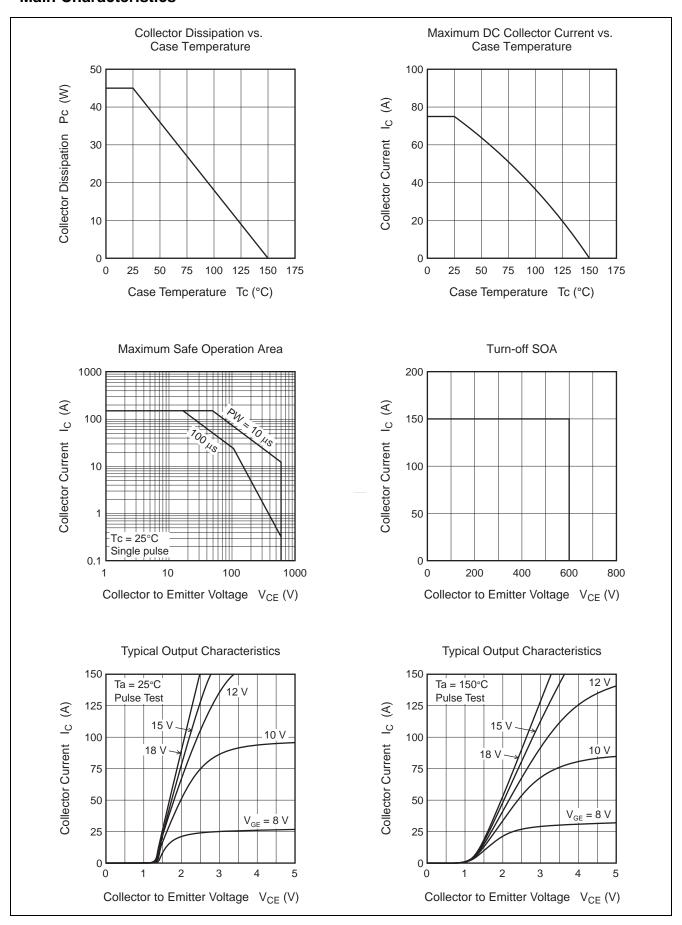
 $(Ta = 25^{\circ}C)$

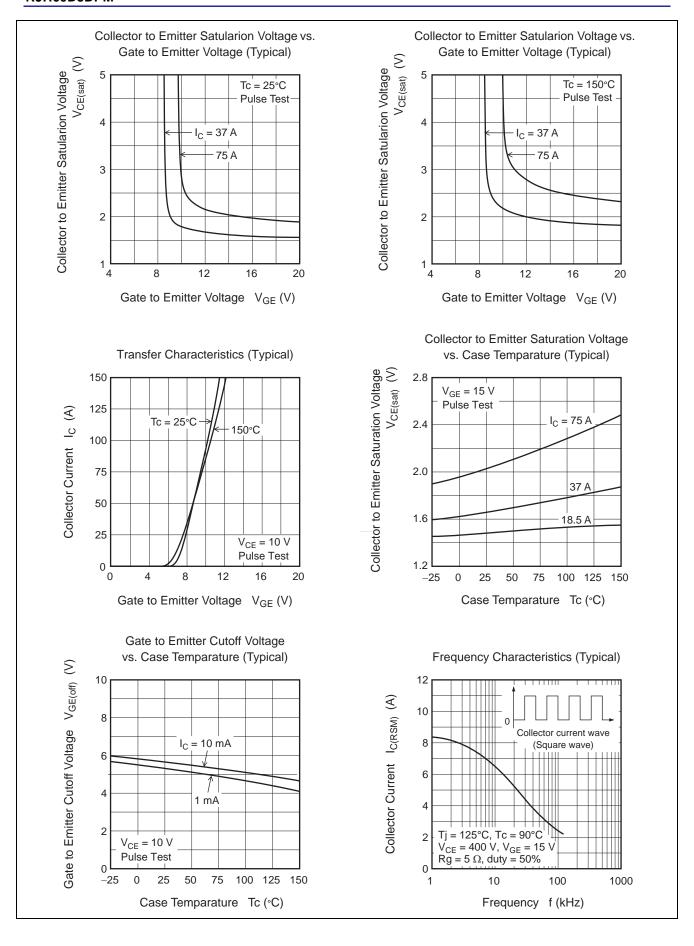
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	V _{BR(CES)}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	V _{CE} = 600 V, V _{GE} = 0
Gate to emitter leak current	I _{GES}		_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	4.0	_	6.0	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$		1.6	2.2	V	$I_C = 37 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	$V_{CE(sat)}$		2.0	_	V	$I_C = 75 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies		1900	_	pF	V _{CE} = 25 V V _{GE} = 0
Output capacitance	Coes	_	120	_	pF	
Reveres transfer capacitance	Cres	_	50	_	pF	f = 1 MHz
Total gate charge	Qg	_	78	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 37 A
Gate to emitter charge	Qge	_	12	_	nC	
Gate to collector charge	Qgc	_	32	_	nC	
Turn-on delay time	t _{d(on)}	_	50	_	ns	V _{CC} = 300 V
Rise time	t _r	_	40	_	ns	V _{GE} = 15 V
Turn-off delay time	t _{d(off)}	_	135	_	ns	$I_C = 37 \text{ A}$ $Rg = 5 \Omega$ Inductive load
Fall time	t _f	_	40	_	ns	
Turn-on energy	Eon	_	0.65	_	mJ	
Turn-off energy	E _{off}	_	0.27	_	mJ	
Total switching energy	E _{total}	_	0.92	_	mJ	
Short circuit withstand time	t _{sc}	3.0	5.0	_	μS	$V_{CC} \leq 360 \text{ V}, \text{ V}_{GE} = 15 \text{ V}$
FRD forward voltage	V _F	_	1.4	1.9	V	I _F = 30 A ^{Note3}
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 30 A
FRD reverse recovery charge	Q _{rr}	_	0.18	_	μС	di _F /dt = 100 A/μs

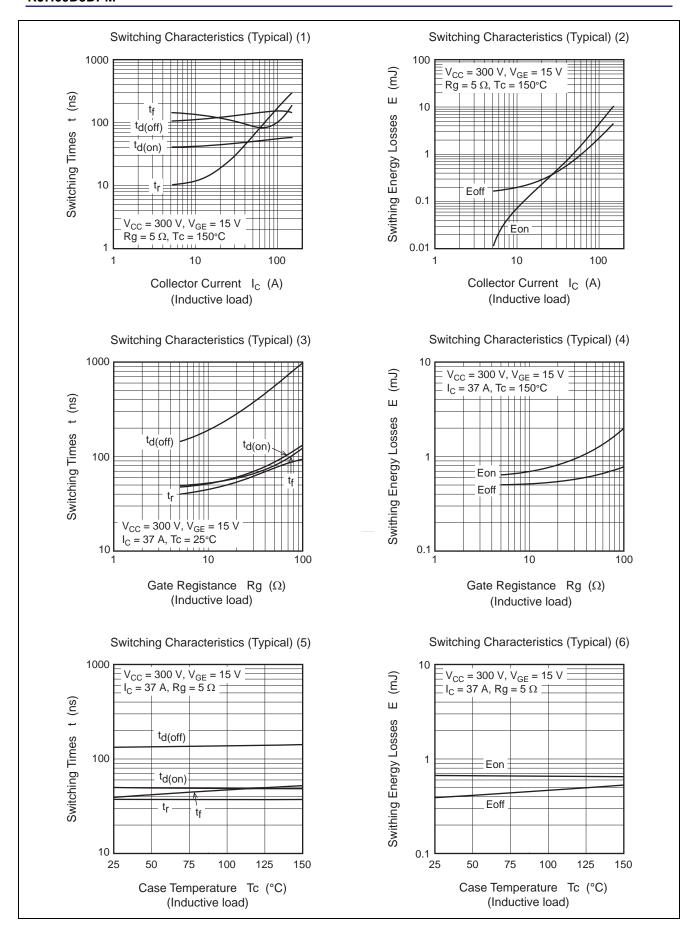
4.2 FRD peak reverse recovery current

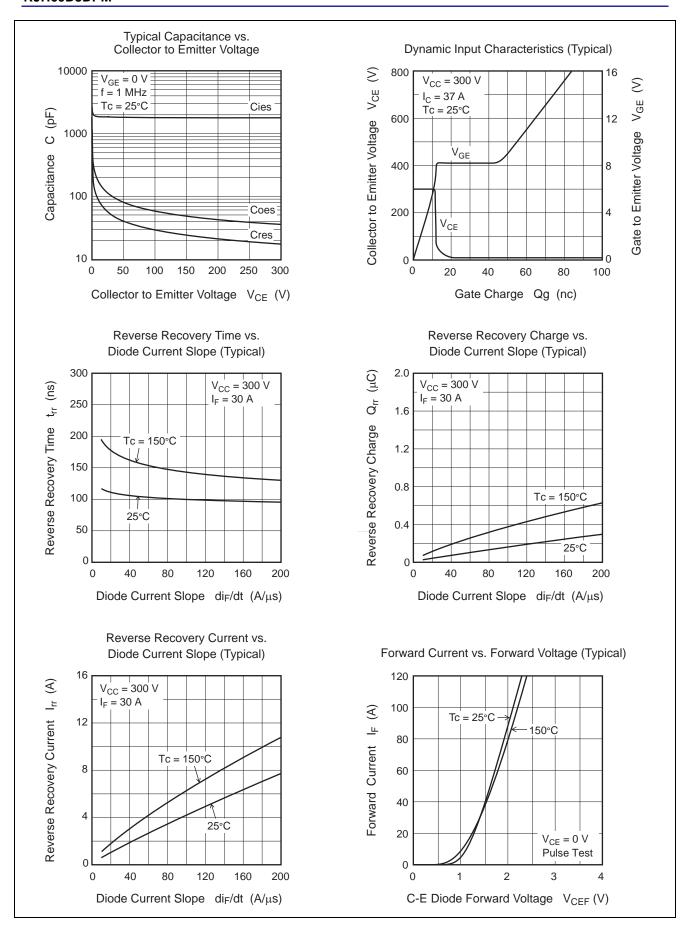
Notes: 3. Pulse test.

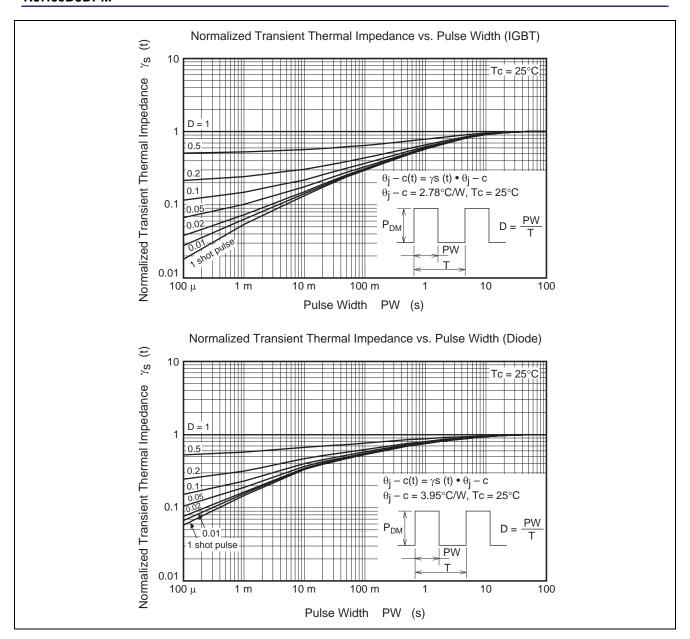
Main Characteristics

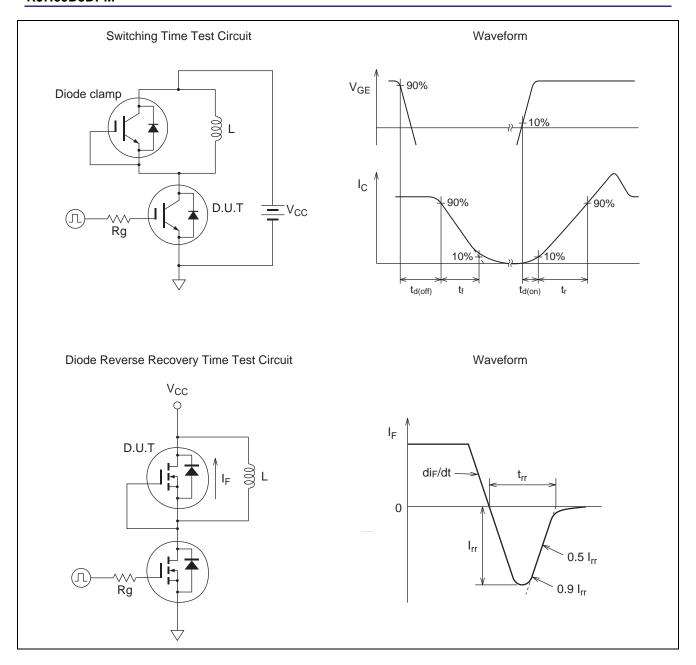




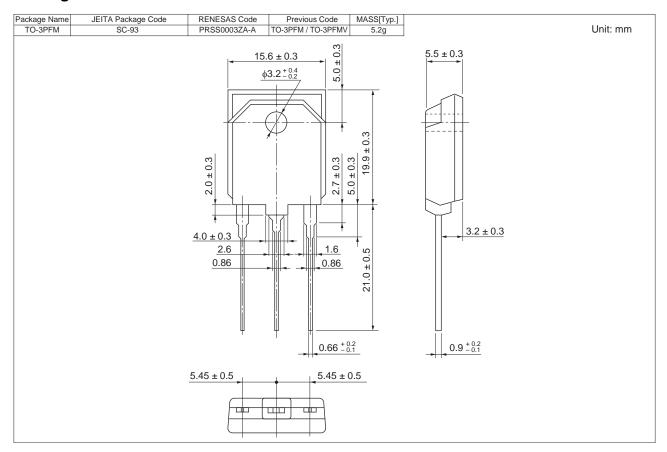








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container
RJH60D5DPM-00#T1	360 pcs	Box (Tube)

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